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				Application Number	W/ 754, 435
				Filing Date	
				First Named Inventor	Sunya Veeraraghavan
				Group Art Unit	2811
				Examiner Name	HUNG JU
Sheet	1	of	1	Attorney Docket Number	SC13065TP

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NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
<u>Vu</u>	AB	Matloubian, "Smart Body Contact for SOI MOSFETs," <i>IEEE SOI Conference</i> , 1989, pp. 128-129.	

Examiner Signature	HUNG JU	Date Considered	11/24/04.
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation, if not in conformance and not considered. Include copy of this form with next communication to applicant.

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